



BIPOLAR ANALOG INTEGRATED CIRCUIT

UPC3227TB

5 V, SILICON GERMANIUM MMIC WIDEBAND AMPLIFIER

DESCRIPTION

The μ PC3227TB is a silicon germanium (SiGe) monolithic integrated circuit designed as IF amplifier for DBS tuners. This IC is manufactured using our 50 GHz f_{\max} UHS2 (Ultra High Speed Process) SiGe bipolar process.

FEATURES

- Low current : $I_{CC} = 4.8 \text{ mA TYP. @ } V_{CC} = 5.0 \text{ V}$
- Output power : $P_{O(\text{sat})} = -1.0 \text{ dBm TYP. @ } f = 1.0 \text{ GHz}$
: $P_{O(\text{sat})} = -3.5 \text{ dBm TYP. @ } f = 2.2 \text{ GHz}$
- High linearity : $P_{O(1\text{dB})} = -6.5 \text{ dBm TYP. @ } f = 1.0 \text{ GHz}$
: $P_{O(1\text{dB})} = -8.0 \text{ dBm TYP. @ } f = 2.2 \text{ GHz}$
- Power gain : $G_P = 22.0 \text{ dB TYP. @ } f = 1.0 \text{ GHz}$
: $G_P = 22.0 \text{ dB TYP. @ } f = 2.2 \text{ GHz}$
- Noise Figure : $NF = 4.7 \text{ dB TYP. @ } f = 1.0 \text{ GHz}$
: $NF = 4.6 \text{ dB TYP. @ } f = 2.2 \text{ GHz}$
- Supply voltage : $V_{CC} = 4.5 \text{ to } 5.5 \text{ V}$
- Port impedance : input/output 50Ω

APPLICATIONS

- IF amplifiers in LNB for DBS converters etc.

ORDERING INFORMATION

Part Number	Order Number	Package	Marking	Supplying Form
μ PC3227TB-E3	μ PC3227TB-E3-A	6-pin super minimold (Pb-Free) ^{Note}	C3P	Embossed tape 8 mm wide. 1, 2, 3 pins face the perforation side of the tape. Qty 3 kpcs/reel.

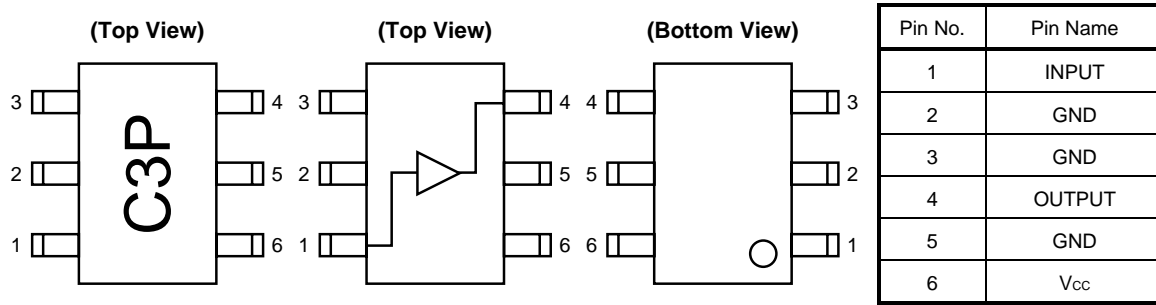
Note With regards to terminal solder (the solder contains lead) plated products (conventionally plated), contact your nearby sales office.

Remark To order evaluation samples, please contact your nearby sales office.
Part number for sample order: μ PC3227TB

Caution Observe precautions when handling because these devices are sensitive to electrostatic discharge.

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.

PIN CONNECTIONS AND INTERNAL BLOCK DIAGRAM



PRODUCT LINE-UP OF 5 V-BIAS SILICON MMIC WIDEBAND AMPLIFIER

(T_A = +25°C, f = 1 GHz, V_{cc} = 5.0 V, Z_s = Z_L = 50 Ω)

Part No.	f _u (GHz)	P _{O(sat)} (dBm)	G _P (dB)	NF (dB)	I _{cc} (mA)	Package	Marking
μPC2711TB	2.9	+1.0	13	5.0	12	6-pin super minimold	C1G
μPC2712TB	2.6	+3.0	20	4.5	12		C1H
μPC3215TB ^{Note}	2.9	+3.5	20.5	2.3	14		C3H
μPC3224TB	3.2	+4.0	21.5	4.3	9.0		C3K
μPC3227TB	3.2	-1.0	22	4.7	4.8		C3P

Note μPC3215TB is f = 1.5 GHz

Remark Typical performance. Please refer to **ELECTRICAL CHARACTERISTICS** in detail.

ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Conditions	Ratings	Unit
Supply Voltage	V _{CC}	T _A = +25°C	6.0	V
Total Circuit Current	I _{CC}	T _A = +25°C	15	mA
Power Dissipation	P _D	T _A = +85°C Note	270	mW
Operating Ambient Temperature	T _A		-40 to +85	°C
Storage Temperature	T _{stg}		-55 to +150	°C
Input Power	P _{in}	T _A = +25°C	+10	dBm

Note Mounted on double-sided copper-clad 50 × 50 × 1.6 mm epoxy glass PWB

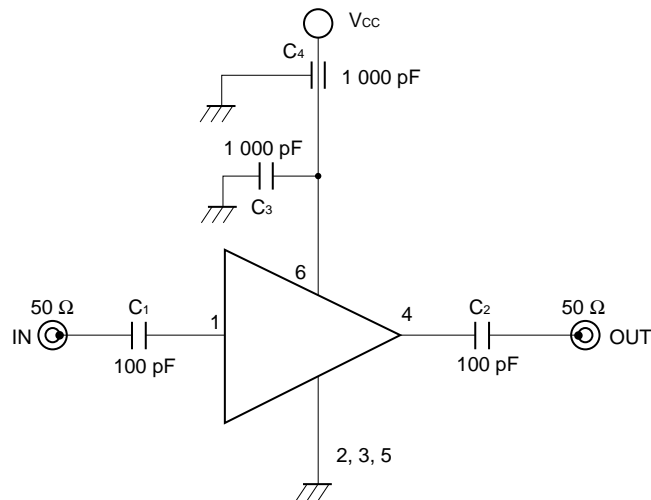
RECOMMENDED OPERATING RANGE

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Supply Voltage	V _{CC}		4.5	5.0	5.5	V
Operating Ambient Temperature	T _A		-40	+25	+85	°C

ELECTRICAL CHARACTERISTICS (T_A = +25°C, V_{CC} = 5.0 V, Z_S = Z_L = 50 Ω)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Circuit Current	I _{CC}	No input signal	4.0	4.8	6.0	mA
Power Gain 1	G _{P1}	f = 0.1 GHz, P _{in} = -40 dBm	20.5	22.5	24.5	dB
Power Gain 2	G _{P2}	f = 1.0 GHz, P _{in} = -40 dBm	19.5	22.0	24.5	
Power Gain 3	G _{P3}	f = 1.8 GHz, P _{in} = -40 dBm	19.0	22.0	25.0	
Power Gain 4	G _{P4}	f = 2.2 GHz, P _{in} = -40 dBm	19.0	22.0	25.0	
Power Gain 5	G _{P5}	f = 2.6 GHz, P _{in} = -40 dBm	19.0	22.0	25.0	
Power Gain 6	G _{P6}	f = 3.0 GHz, P _{in} = -40 dBm	18.0	21.0	24.5	
Saturated Output Power 1	P _{O(sat)1}	f = 1.0 GHz, P _{in} = -12 dBm	-3.5	-1.0	-	dBm
Saturated Output Power 2	P _{O(sat)2}	f = 2.2 GHz, P _{in} = -12 dBm	-6.0	-3.5	-	
Gain 1 dB Compression Output Power 1	P _{O(1dB)1}	f = 1.0 GHz	-9.0	-6.5	-	dBm
Gain 1 dB Compression Output Power 2	P _{O(1dB)2}	f = 2.2 GHz	-11.0	-8.0	-	
Noise Figure 1	NF1	f = 1.0 GHz	-	4.7	5.5	dB
Noise Figure 2	NF2	f = 2.2 GHz	-	4.6	5.5	
Isolation 1	ISL1	f = 1.0 GHz, P _{in} = -40 dBm	35	40	-	dB
Isolation 2	ISL2	f = 2.2 GHz, P _{in} = -40 dBm	35	43	-	
Input Return Loss 1	RL _{in1}	f = 1.0 GHz, P _{in} = -40 dBm	7.5	10.5	-	dB
Input Return Loss 2	RL _{in2}	f = 2.2 GHz, P _{in} = -40 dBm	7.5	10.5	-	
Output Return Loss 1	RL _{out1}	f = 1.0 GHz, P _{in} = -40 dBm	10.0	13.5	-	dB
Output Return Loss 2	RL _{out2}	f = 2.2 GHz, P _{in} = -40 dBm	7.5	9.5	-	
Input 3rd Order Distortion Intercept Point 1	IIP ₃₁	f1 = 1 000 MHz, f2 = 1 001 MHz, P _{in} = -40 dBm	-	-18.0	-	dBm
Input 3rd Order Distortion Intercept Point 2	IIP ₃₂	f1 = 2 200 MHz, f2 = 2 201 MHz, P _{in} = -40 dBm	-	-20.5	-	
Output 3rd Order Distortion Intercept Point 1	OIP ₃₁	f1 = 1 000 MHz, f2 = 1 001 MHz, P _{in} = -40 dBm	-	+4.0	-	dBm
Output 3rd Order Distortion Intercept Point 2	OIP ₃₂	f1 = 2 200 MHz, f2 = 2 201 MHz, P _{in} = -40 dBm	-	+1.5	-	
2nd Order Intermodulation Distortion	IM ₂	f1 = 1 000 MHz, f2 = 1 001 MHz, P _{in} = -40 dBm	-	30.5	-	dBc
K factor 1	K1	f = 1.0 GHz	-	3.8	-	-
K factor 2	K2	f = 2.2 GHz	-	3.9	-	-

TEST CIRCUIT



The application circuits and their parameters are for reference only and are not intended for use in actual design-ins.

**COMPONENTS OF TEST CIRCUIT FOR MEASURING
ELECTRICAL CHARACTERISTICS**

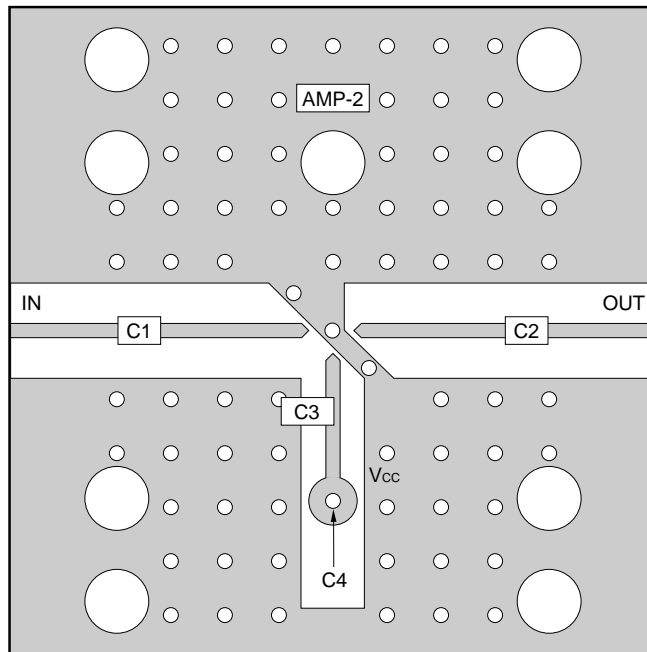
	Type	Value
C1, C2	Chip Capacitor	100 pF
C3	Chip Capacitor	1 000 pF
C4	Feed-through Capacitor	1 000 pF

CAPACITORS FOR V_{CC} AND INPUT PINS

Bypass capacitor for V_{CC} pin is intended to minimize V_{CC} pin's ground impedance. Therefore, stable bias can be supplied against V_{CC} fluctuation.

Coupling capacitors for input/output pins are intended to minimize RF serial impedance and cut DC.

ILLUSTRATION OF THE TEST CIRCUIT ASSEMBLED ON EVALUATION BOARD



COMPONENT LIST

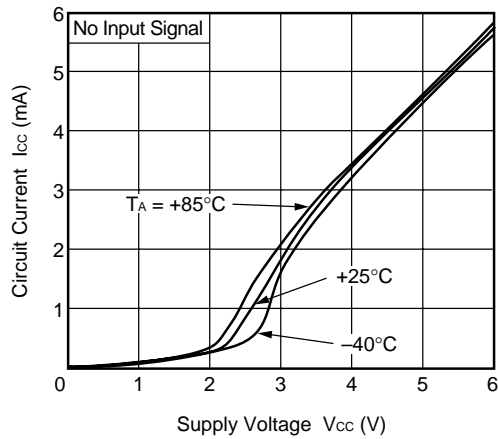
	Value
C1, C2	100 pF
C3, C4	1 000 pF

Notes

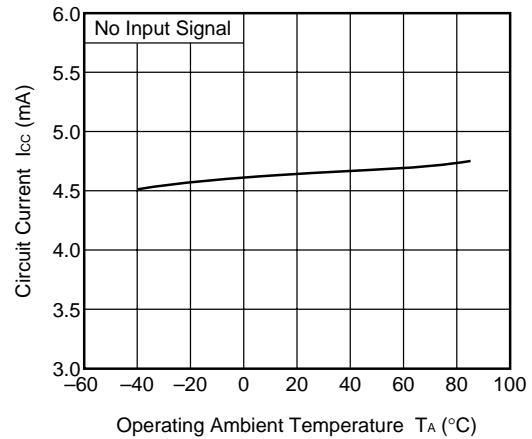
1. 30 × 30 × 0.4 mm double sided copper clad polyimide board.
2. Back side: GND pattern
3. Solder plated on pattern
4. o○: Through holes

TYPICAL CHARACTERISTICS ($T_A = +25^\circ\text{C}$, $V_{CC} = 5.0\text{ V}$, $Z_s = Z_L = 50\ \Omega$, unless otherwise specified)

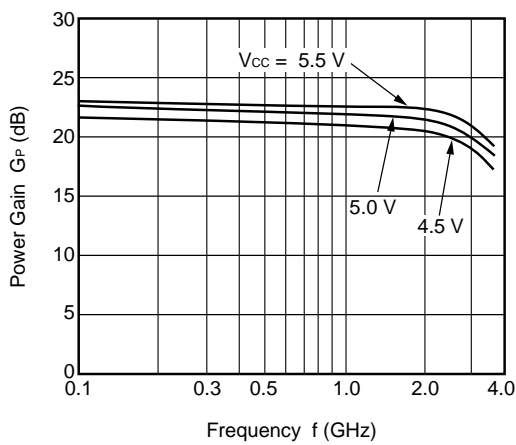
CIRCUIT CURRENT vs. SUPPLY VOLTAGE



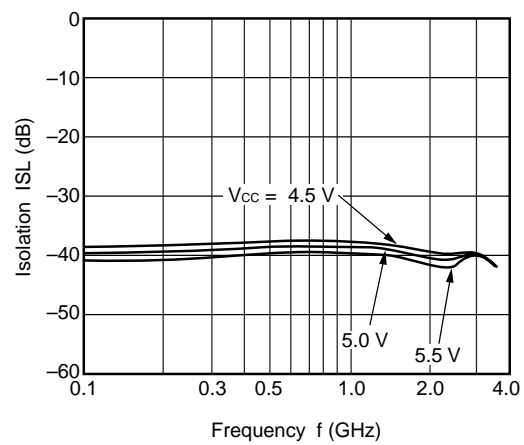
CIRCUIT CURRENT vs. OPERATING AMBIENT TEMPERATURE



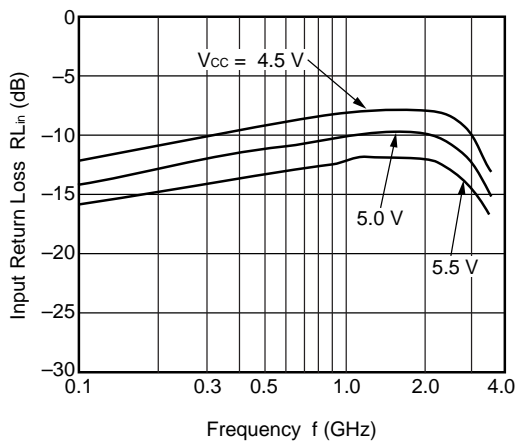
POWER GAIN vs. FREQUENCY



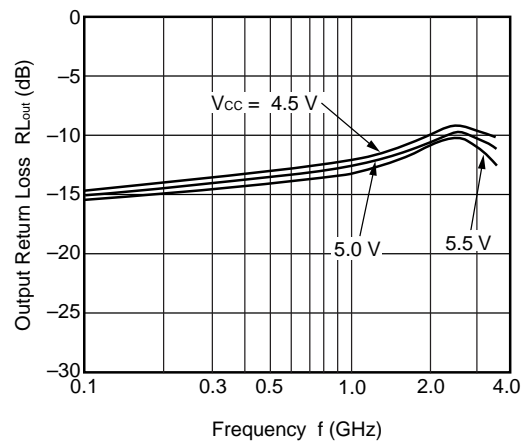
ISOLATION vs. FREQUENCY



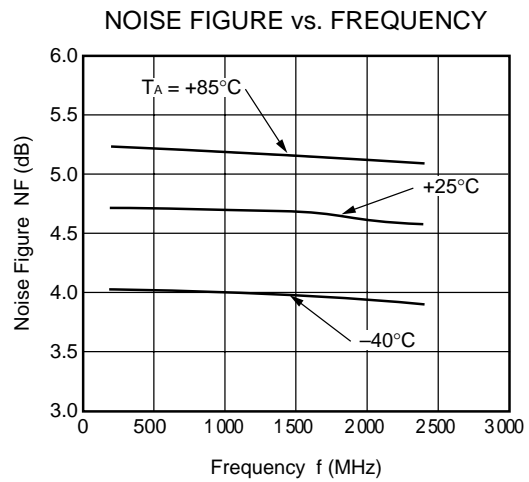
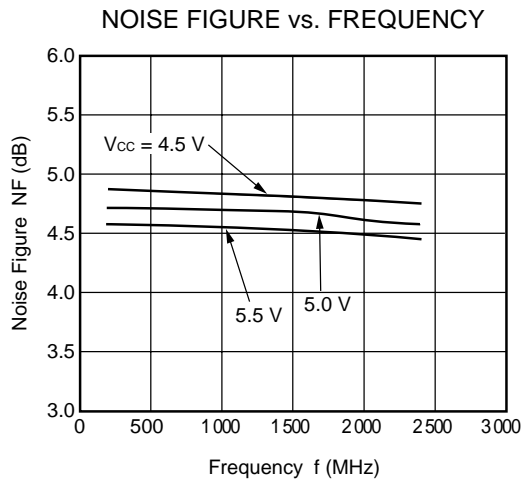
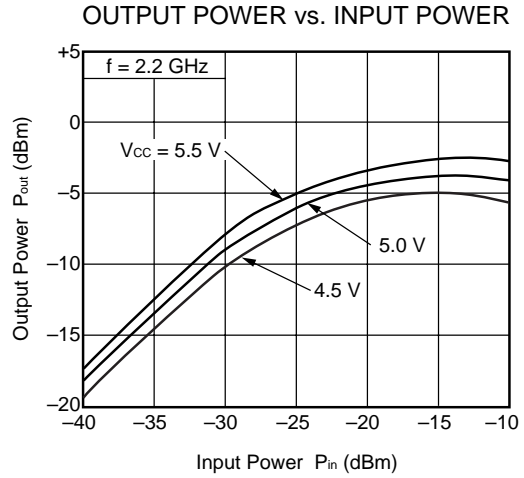
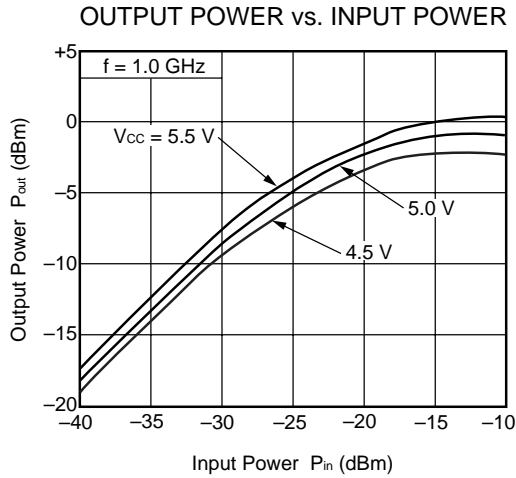
INPUT RETURN LOSS vs. FREQUENCY



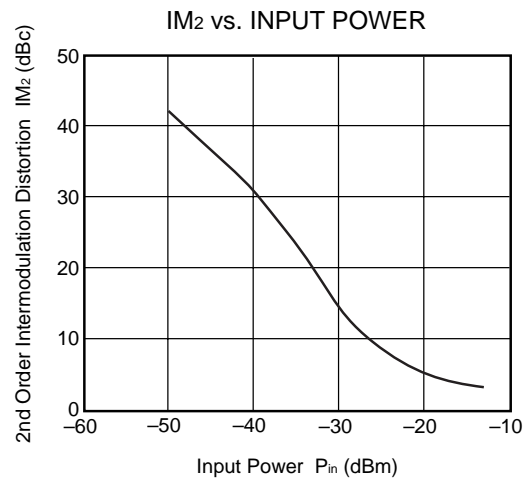
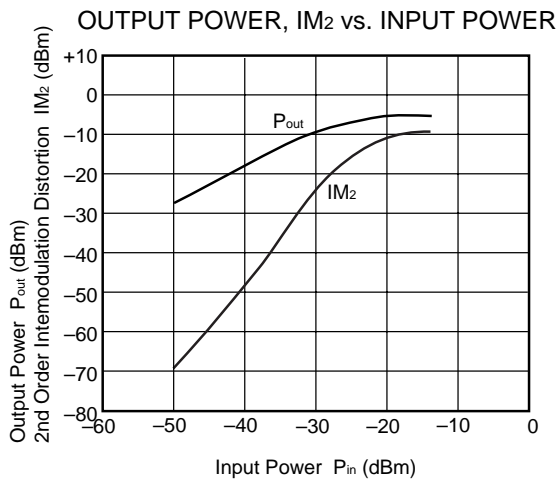
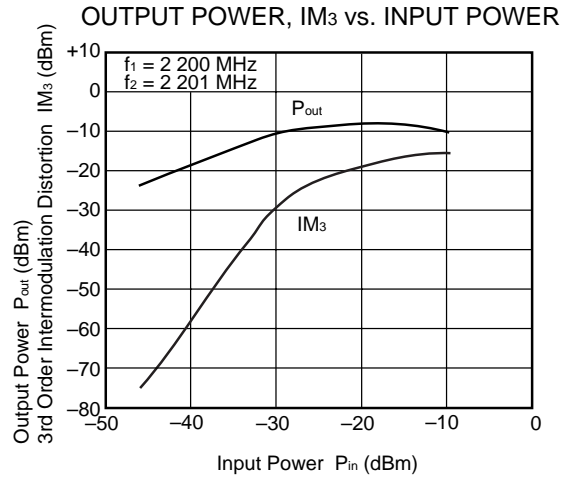
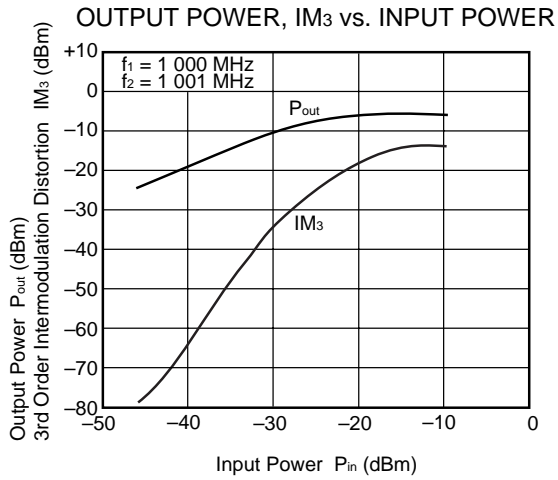
OUTPUT RETURN LOSS vs. FREQUENCY



Remark The graphs indicate nominal characteristics.



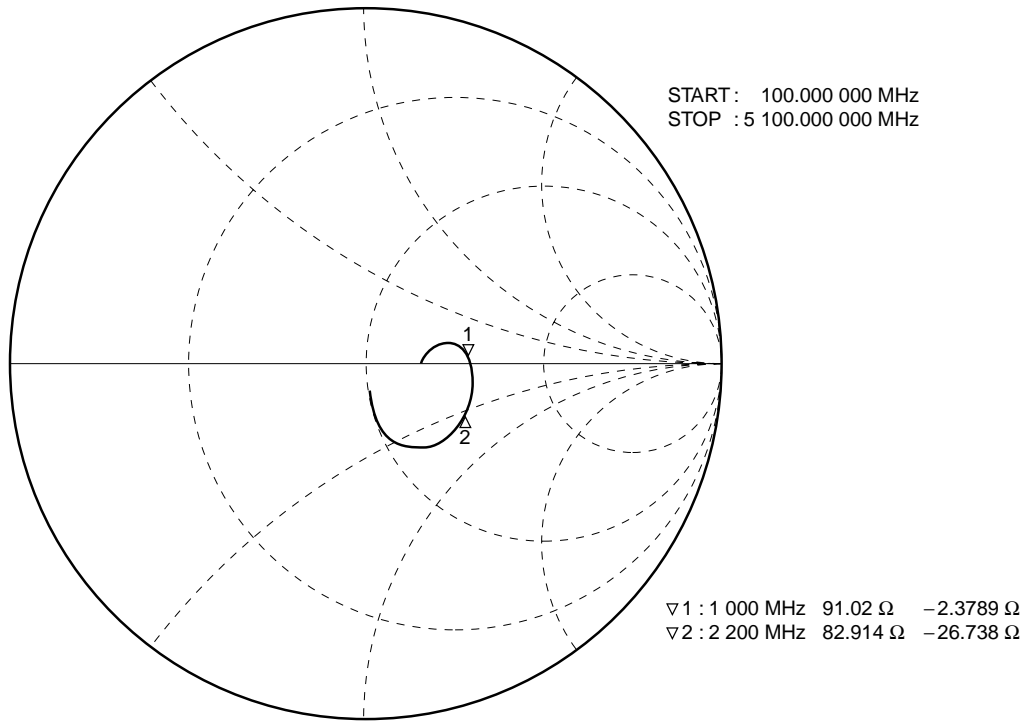
Remark The graphs indicate nominal characteristics.



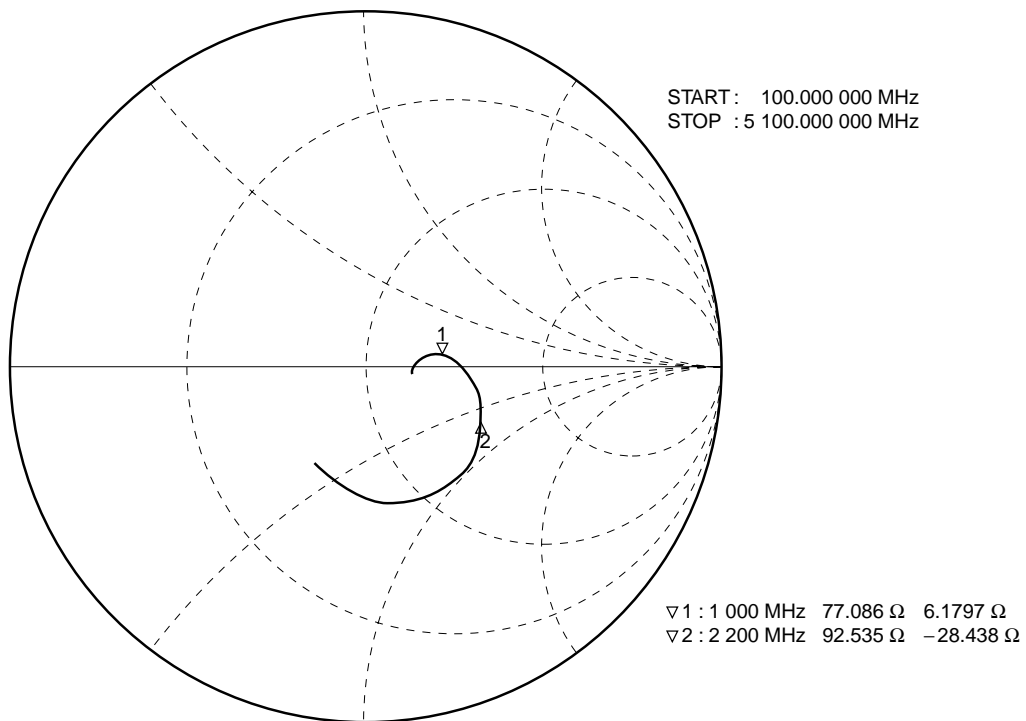
Remark The graphs indicate nominal characteristics.

S-PARAMETERS (T_A = +25°C, V_{CC} = 5.0 V, P_{in} = -40 dBm)

S₁₁-FREQUENCY

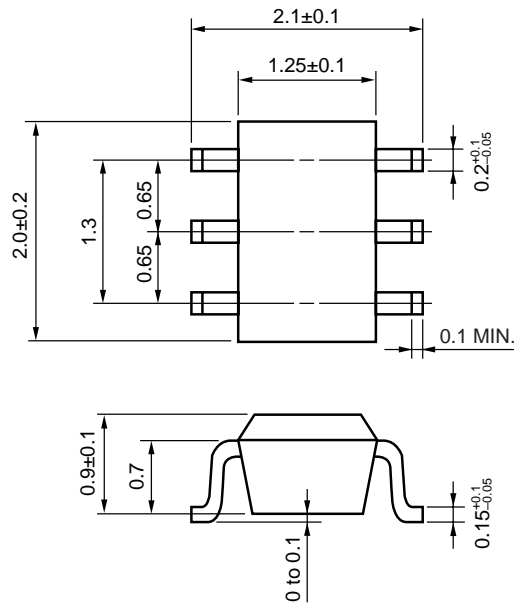


S₂₂-FREQUENCY



PACKAGE DIMENSIONS

6-PIN SUPER MINIMOLD (UNIT: mm)



NOTES ON CORRECT USE

- (1) Observe precautions for handling because of electro-static sensitive devices.
- (2) Form a ground pattern as widely as possible to minimize ground impedance (to prevent undesired oscillation).
All the ground terminals must be connected together with wide ground pattern to decrease impedance difference.
- (3) The bypass capacitor should be attached to the Vcc line.
- (4) The DC cut capacitor must be attached to input and output pin.

RECOMMENDED SOLDERING CONDITIONS

This product should be soldered and mounted under the following recommended conditions. For soldering methods and conditions other than those recommended below, contact your nearby sales office.

Soldering Method	Soldering Conditions	Condition Symbol
Infrared Reflow	Peak temperature (package surface temperature) : 260°C or below Time at peak temperature : 10 seconds or less Time at temperature of 220°C or higher : 60 seconds or less Preheating time at 120 to 180°C : 120±30 seconds Maximum number of reflow processes : 3 times Maximum chlorine content of rosin flux (% mass) : 0.2%(Wt.) or below	IR260
Wave Soldering	Peak temperature (molten solder temperature) : 260°C or below Time at peak temperature : 10 seconds or less Preheating temperature (package surface temperature) : 120°C or below Maximum number of flow processes : 1 time Maximum chlorine content of rosin flux (% mass) : 0.2%(Wt.) or below	WS260
Partial Heating	Peak temperature (terminal temperature) : 350°C or below Soldering time (per side of device) : 3 seconds or less Maximum chlorine content of rosin flux (% mass) : 0.2%(Wt.) or below	HS350

Caution Do not use different soldering methods together (except for partial heating).

Subject: Compliance with EU Directives

CEL certifies, to its knowledge, that semiconductor and laser products detailed below are compliant with the requirements of European Union (EU) Directive 2002/95/EC Restriction on Use of Hazardous Substances in electrical and electronic equipment (RoHS) and the requirements of EU Directive 2003/11/EC Restriction on Penta and Octa BDE.

CEL Pb-free products have the same base part number with a suffix added. The suffix –A indicates that the device is Pb-free. The –AZ suffix is used to designate devices containing Pb which are exempted from the requirement of RoHS directive (*). In all cases the devices have Pb-free terminals. All devices with these suffixes meet the requirements of the RoHS directive.

This status is based on CEL’s understanding of the EU Directives and knowledge of the materials that go into its products as of the date of disclosure of this information.

Restricted Substance per RoHS	Concentration Limit per RoHS (values are not yet fixed)	Concentration contained in CEL devices	
		-A	-AZ
Lead (Pb)	< 1000 PPM	Not Detected	(*)
Mercury	< 1000 PPM	Not Detected	
Cadmium	< 100 PPM	Not Detected	
Hexavalent Chromium	< 1000 PPM	Not Detected	
PBB	< 1000 PPM	Not Detected	
PBDE	< 1000 PPM	Not Detected	

If you should have any additional questions regarding our devices and compliance to environmental standards, please do not hesitate to contact your local representative.

Important Information and Disclaimer: Information provided by CEL on its website or in other communications concerning the substance content of its products represents knowledge and belief as of the date that it is provided. CEL bases its knowledge and belief on information provided by third parties and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. CEL has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. CEL and CEL suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall CEL’s liability arising out of such information exceed the total purchase price of the CEL part(s) at issue sold by CEL to customer on an annual basis.

See CEL Terms and Conditions for additional clarification of warranties and liability.